TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

# **TPC8053-H**

Switching Regulator Applications Motor Drive Applications **DC-DC Converter Applications** 

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge:  $Q_{SW} = 6.7 \text{ nC}$  (typ.)
- Low drain-source ON-resistance:

 $R_{DS(ON)} = 14.1 \text{ m}\Omega \text{ (typ.)}$ 

- High forward transfer admittance:  $|Y_{fs}| = 30 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 60 \ V)$
- Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.2 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

| Characte                   | eristic                                 | Symbol           | Rating     | Unit |
|----------------------------|---|------------------|------------|------|
| Drain-source voltage       |   | V <sub>DSS</sub> | 60         | V    |
| Drain-gate voltage (R      | t <sub>GS</sub> = 20 kΩ)                | V <sub>DGR</sub> | 60         | V    |
| Gate-source voltage        |   | V <sub>GSS</sub> | ±20        | V    |
| Drain current              | DC (Note 1)                             | ID               | 9          | ^    |
|                            | Pulsed (Note 1)                         | I <sub>DP</sub>  | 36         | A    |
| Drain power dissipation    | on (t = 10 s)<br>(Note 2a)              | PD               | 1.9        | W    |
| Drain power dissipation    | on (t = 10 s)<br>(Note 2b)              | PD               | 1.0        | W    |
| Single-pulse avalancl      | ne energy<br>(Note 3)                   | E <sub>AS</sub>  | 29         | mJ   |
| Avalanche current          |   | I <sub>AR</sub>  | 9          | А    |
| Repetitive avalanche<br>(1 | energy<br><sup>-</sup> c=25°C) (Note 4) | E <sub>AR</sub>  | 0.06       | mJ   |
| Channel temperature        |   | T <sub>ch</sub>  | 150        | °C   |
| Storage temperature        | range                                   | T <sub>stg</sub> | -55 to 150 | °C   |

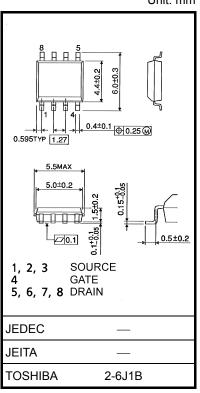
Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the

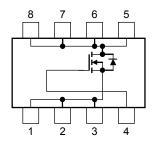
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.085g (typ.)

### **Circuit Configuration**



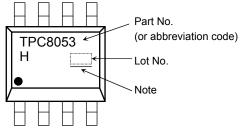
Unit: mm

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## Thermal Characteristics

| Characteristic   | Symbol                 | Max  | Unit |  |
|--|------------------------|------|------|--|
| $\label{eq:thermal} \begin{array}{l} \mbox{Thermal resistance, channel to ambient} \\ (t=10 \ s) & (\mbox{Note 2a}) \end{array}$ | R <sub>th (ch-a)</sub> | 65.8 | °C/W |  |
| $\label{eq:thermal} \begin{array}{l} \mbox{Thermal resistance, channel to ambient} \\ (t=10 \ s) & (\mbox{Note 2b}) \end{array}$ | R <sub>th (ch-a)</sub> | 125  | °C/W |  |

## Marking (Note 5)

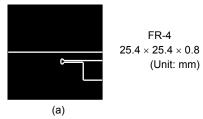


Note: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

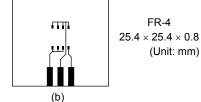
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)





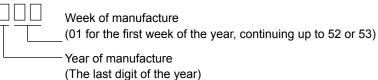
(b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD} = 24 V$ ,  $T_{ch} = 25^{\circ}C$  (initial),  $L = 500 \mu H$ ,  $R_G = 25 \Omega$ ,  $I_{AR} = 9 A$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)



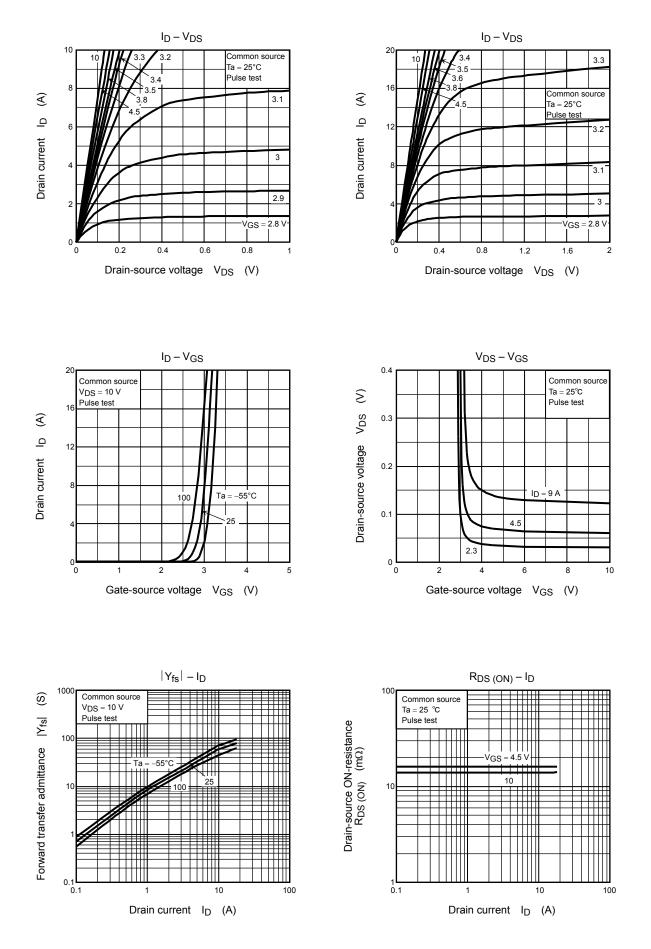
**Electrical Characteristics (Ta = 25°C)** 

| Characteristic                 |                            | Symbol               | Test Condition   | Min | Тур. | Max  | Unit |
|--------------------------------|----------------------------|----------------------|--|-----|------|------|------|
| Gate leakage cur               | rent                       | I <sub>GSS</sub>     | $V_{GS}=\pm 20~V,~V_{DS}=0~V$  |     |      | ±100 | nA   |
| Drain cutoff curre             | ent                        | I <sub>DSS</sub>     | $V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$                            |     |      | 10   | μA   |
| Drain-source breakdown voltage |                            | V (BR) DSS           | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$                                      | 60  |      | _    | V    |
|                                |                            | V (BR) DSX           | $I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$                                    | 43  |      | _    |      |
| Gate threshold vo              | oltage                     | V <sub>th</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.2 \text{ mA}$                          | 1.3 |      | 2.3  | V    |
| Drain-source ON-resistance     |                            | Pro (out)            | $V_{GS} = 4.5 \text{ V}, I_D = 4.5 \text{ A}$                                    | _   | 15.8 | 24.2 | mΩ   |
|                                |                            | R <sub>DS</sub> (ON) | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$                           |     | 14.1 | 22.5 |      |
| Forward transfer               | admittance                 | Y <sub>fs</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$                           | 15  | 30   | _    | S    |
| Input capacitance              |                            | C <sub>iss</sub>     |  |     | 1620 | 2110 | pF   |
| Reverse transfer capacitance   |                            | C <sub>rss</sub>     | V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz                         |     | 60   | 90   |      |
| Output capacitance             |                            | C <sub>oss</sub>     |  |     | 200  | _    |      |
| Gate resistance                |                            | rg                   | $V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 5 \text{ MHz}$ | _   | 2.3  | 3.5  | Ω    |
| Switching time                 | Rise time                  | tr                   | $V_{GS} \stackrel{10}{}_{0} V \qquad I_{D} = 4.5 A$                              | _   | 2.4  |      | ns   |
|                                | Turn-on time               | t <sub>on</sub>      |  | _   | 9.1  | _    |      |
|                                | Fall time                  | t <sub>f</sub>       |  | _   | 7.0  |      |      |
|                                | Turn-off time              | t <sub>off</sub>     | $V_{DD}\approx 30 \text{ V}$ Duty $\leq$ 1%, $t_W=10 \ \mu s$                    | _   | 34   | _    |      |
| Total gate charge              |                            | Qg                   | $V_{DD}\approx 48~V,~V_{GS}=10~V,~I_{D}=9~A$                                     |     | 25   | _    |      |
| (gate-source plus              | te-source plus gate-drain) |                      | $V_{DD}\approx 48~V,~V_{GS}=5~V,~I_{D}=9~A$                                      |     | 13   | _    |      |
| Gate-source charge 1           |                            | Q <sub>gs1</sub>     |  |     | 5.2  |      | nC   |
| Gate-drain ("Miller") charge   |                            | Q <sub>gd</sub>      | $V_{DD} \approx 48$ V, $V_{GS} = 10$ V, $I_D = 9$ A                              |     | 4.5  |      |      |
| Gate switch char               | ge                         | Q <sub>SW</sub>      | 1  |     | 6.7  | _    |      |

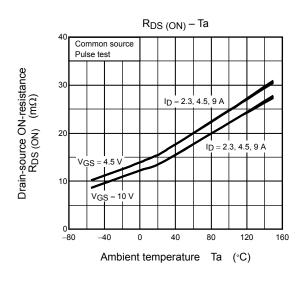
### Source-Drain Ratings and Characteristics (Ta = 25°C)

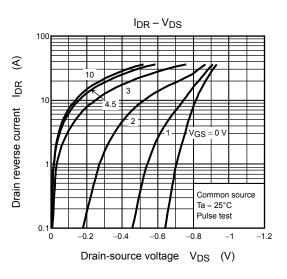
| Characteristic          |       | Symbol   | Test Condition   | Min  | Тур. | Max | Unit |   |
|-------------------------|-------|----------|------------------|--|------|-----|------|---|
| Peak forward current    | Pulse | (Note 1) | I <sub>FP</sub>  | —  | _    |     | 36   | А |
| Forward voltage (diode) |       |          | V <sub>DSF</sub> | $I_{DR} = 9 \text{ A}, V_{GS} = 0 \text{ V}$ |      |     | -1.2 | V |

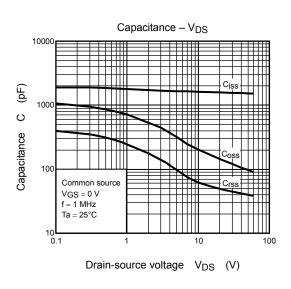
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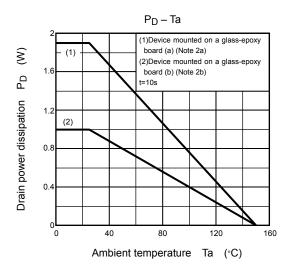


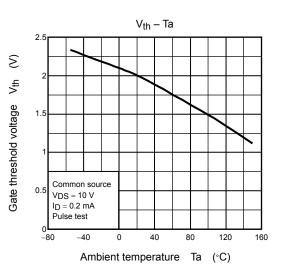
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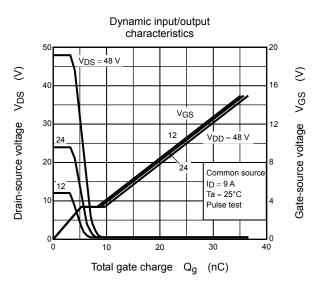


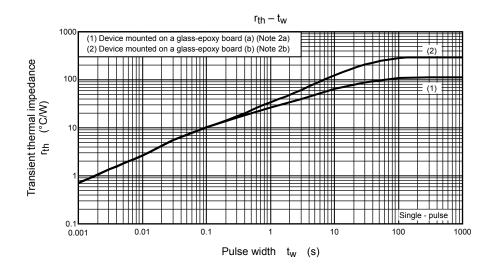


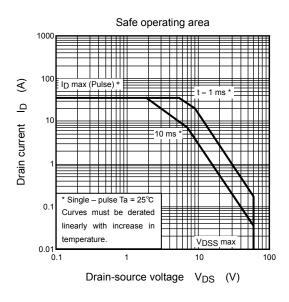












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